
CMOS ANALOG INTEGRATED FILTERS

2001. 7. 5.

JOONGHO CHOI

Department of Electrical Engineering

University of Seoul

jchoi@ee.uos.ac.kr

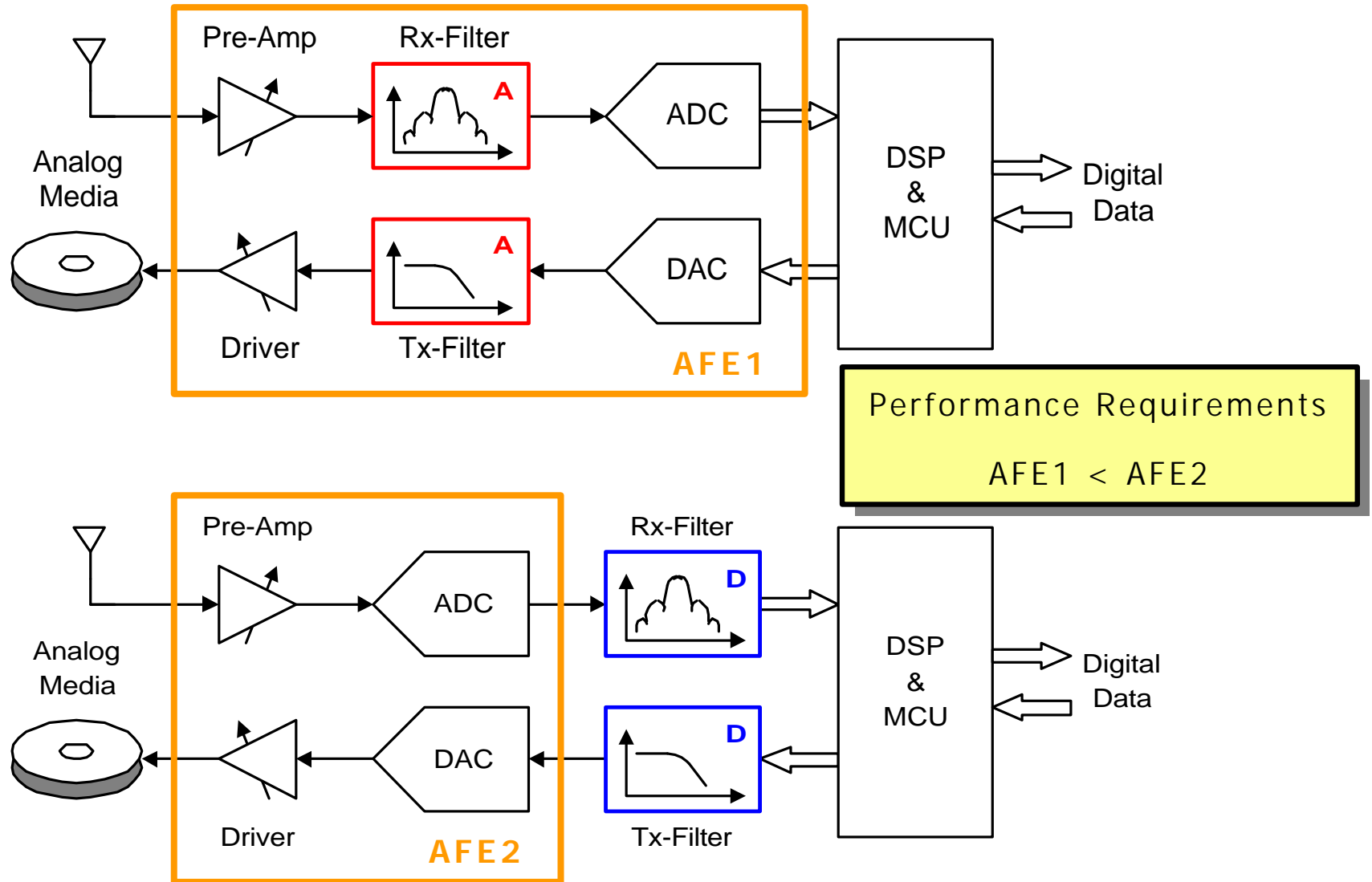
OUTLINE

- **Introduction to Analog Integrated Filters**
- **Introduction to Transconductance (Gm)-C Filters**
 - ✓ Transconductance Circuits
 - ✓ High-Order Gm-C Filters
 - ✓ Design Issues for Gm-C Filters
 - ✓ Design Examples
- **Introduction to Switched-Capacitor (SC) Filters**
 - ✓ Switched-Capacitor Integrators
 - ✓ High-Order SC Filters
 - ✓ Design Issues for SC Filters
 - ✓ Design Examples
- **Simulation Exercises**



Introduction

Mixed-Signal Systems



Analog Integrated Filters

- **Analog Filters vs Digital Filters**

 - :-) Speed, Power Dissipation, Silicon Area

 - :-(Dynamic Range, Programmability, Controllability

- **Continuous-Time Filters**

 - ➔ Gm-C Filter, MOSFET-C Filter, Active R-C Filter, ...

 - ➔ No Pre- & Post- Processing Required

 - ➔ **Tuning Circuits** Required

- **Discrete-Time Filters**

 - ➔ Switched-Capacitor (SC) Filter, Switched-Current Filter

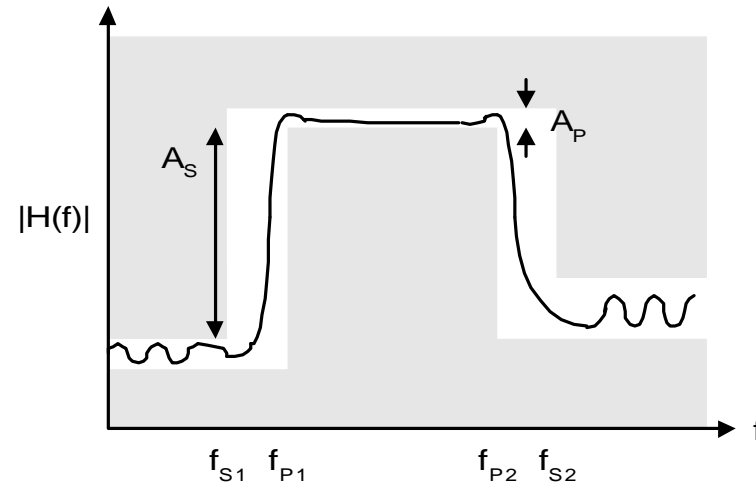
 - ➔ Pre- & Post- Processing Required

 - ➔ Desirably Accurate



Filter Frequency Response

- Magnitude Characteristics



- Phase Characteristics

- Operating Types

- Lowpass, Highpass, Bandpass, Bandreject, Allpass
- Frequency Transformation from LPF Prototype

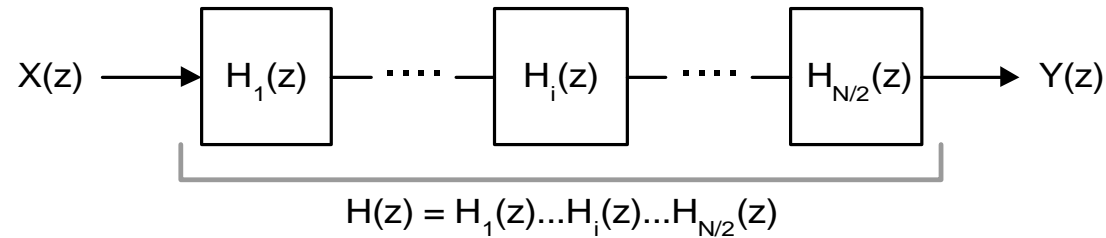
- Response Types

- Butterworth, Chebyshev (I,II), Elliptic, Equiripple



High-Order Filter Implementation 1

Cascading of Biquad Blocks



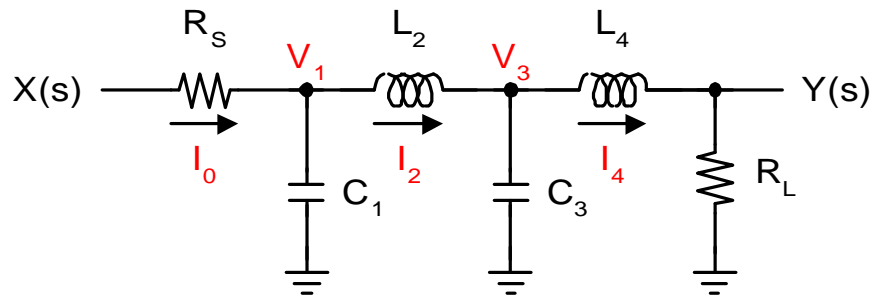
$$H(z) = \prod_{i=1}^{N/2} H_i(z) = \prod_{i=1}^{N/2} \frac{b_2 z^2 + b_1 z + b_0}{a_2 z^2 + a_1 z + a_0}$$

- Easy Adjustment of Frequency Characteristics
- Pole/Zero Pair Matching
- Biquad Permutation
- Gain Distribution



High-Order Filter Implementation 2

RLC Prototype



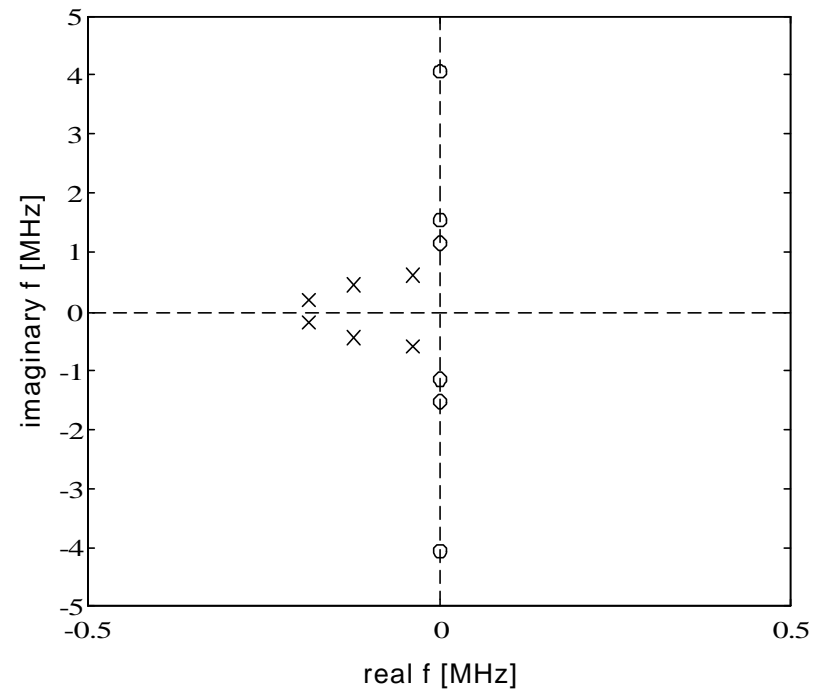
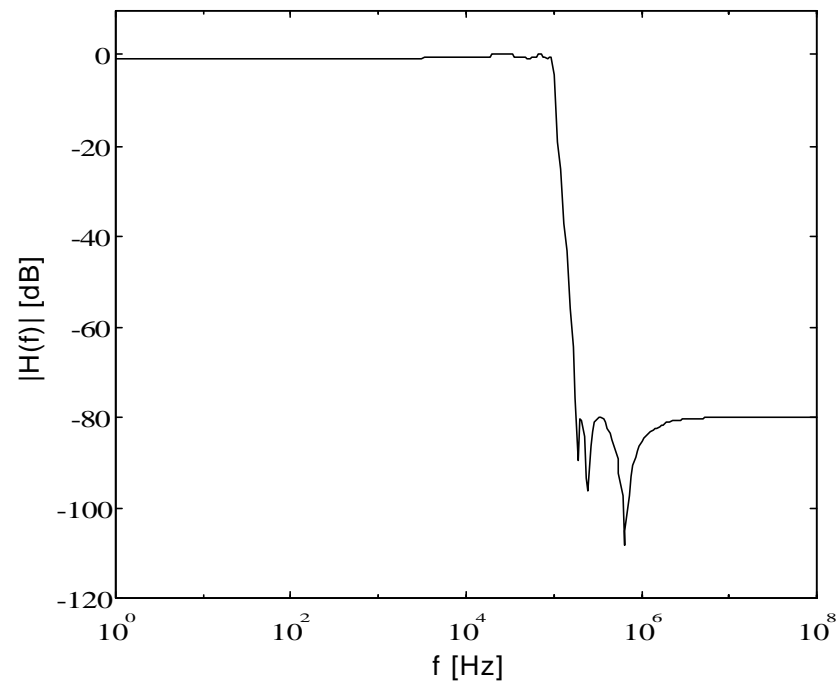
$$\begin{aligned} I_0 &= (X - V_1)/R_s \\ V_1 &= (I_0 - I_2)/sC_1 \\ I_2 &= (V_1 - V_3)/sL_2 \\ V_3 &= (I_2 - I_4)/sC_3 \\ I_4 &= (V_3 - I_4 R_L)/sL_4 \end{aligned}$$

- Implemented with Many Integrators
- Less Sensitive to Variations of Components
- Easy to Obtain
- Frequency Transformation
- Impedance Transformation



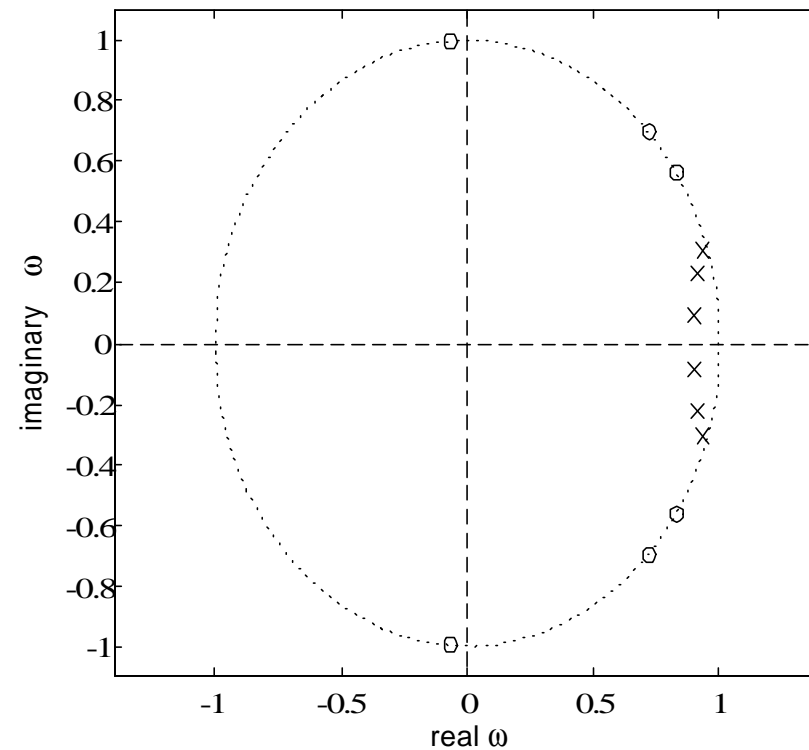
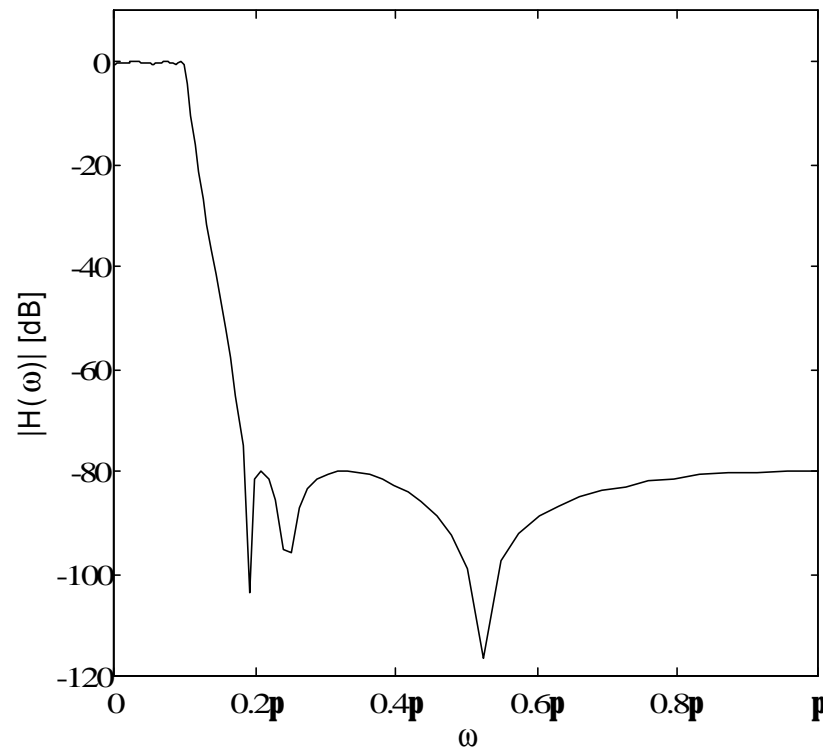
Continuous-Time Filter Response

$$H(s) \equiv \frac{X(s)}{Y(s)} = \frac{b_1 s^M + b_2 s^{M-1} + \dots + b_M s + b_{M+1}}{a_1 s^N + a_2 s^{N-1} + \dots + a_N s + a_{N+1}}$$



Discrete-Time Filter Response

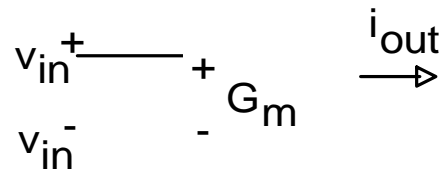
$$H(z) = \frac{N(z)}{D(z)} = \frac{b_1 z^M + b_2 z^{M-1} + \cdots + b_M z + b_{M+1}}{a_1 z^N + a_2 z^{N-1} + \cdots + a_M z + a_{M+1}}$$



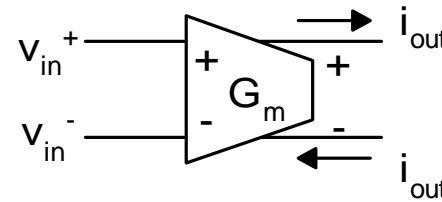
Continuous-Time Filter (Gm-C Filter)

Gm Amplifier Basics

● Transconductance (Gm) Amplifier



Single-Ended



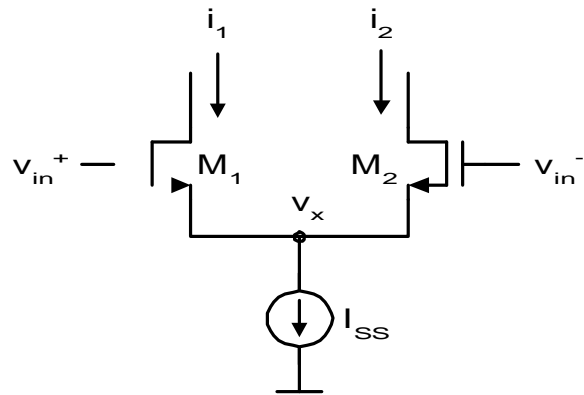
Fully-Differential

● Transconductance Amplifier Characteristics

- Linearity $i_{out} \equiv G_m \cdot v_{in} = G_m \cdot (v_{in}^+ - v_{in}^-)$
- I/O Impedances $R_{in} = \infty, R_{out} = \infty$
- Operating (Dynamic) Range
- Frequency Characteristics
- Electrically Programmable Gm Value

Gm Amp Circuit Examples

● Simple Differential Pair Example

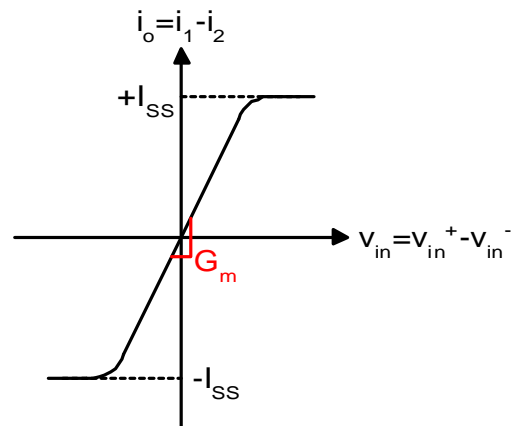


$$i_1 = \frac{\beta}{2} (v_{in}^+ - v_x - V_{TH})^2$$

$$i_2 = \frac{\beta}{2} (v_{in}^- - v_x - V_{TH})^2$$

$$\left. \begin{array}{l} i_1 \\ i_2 \end{array} \right\} \rightarrow i_1 + i_2 = I_{SS}$$

$$i_{out} \equiv i_1 - i_2 = \frac{\beta}{2} v_{in} \sqrt{\frac{2I_{SS}}{\beta/2} - v_{in}^2}$$



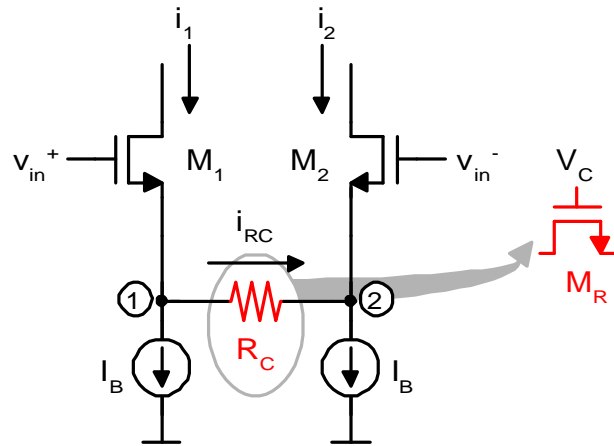
for large I_{SS} , small β & v_{in}

$$i_{out} \approx \sqrt{\beta I_{SS}} \cdot v_{in}$$

$$\therefore G_m \equiv \sqrt{\beta I_{SS}}$$



● Differential Pair w/ Degenerate Resistor Example



$$\begin{aligned} i_1 &= i_{R_C} + I_B \\ i_2 + i_{R_C} &= I_B \end{aligned} \quad \left. \vphantom{\begin{aligned} i_1 &= i_{R_C} + I_B \\ i_2 + i_{R_C} &= I_B \end{aligned}} \right\} \longrightarrow i_1 - i_2 = 2 \cdot i_{R_C}$$

$$v_{in}^+ - v_{gs1} - i_{R_C} R_C + v_{gs2} = v_{in}^-$$

$$\therefore i_{out} \equiv i_1 - i_2 = \frac{2}{R_C} \left\{ \Delta v_{in} - (v_{gs1} - v_{gs2}) \right\}$$

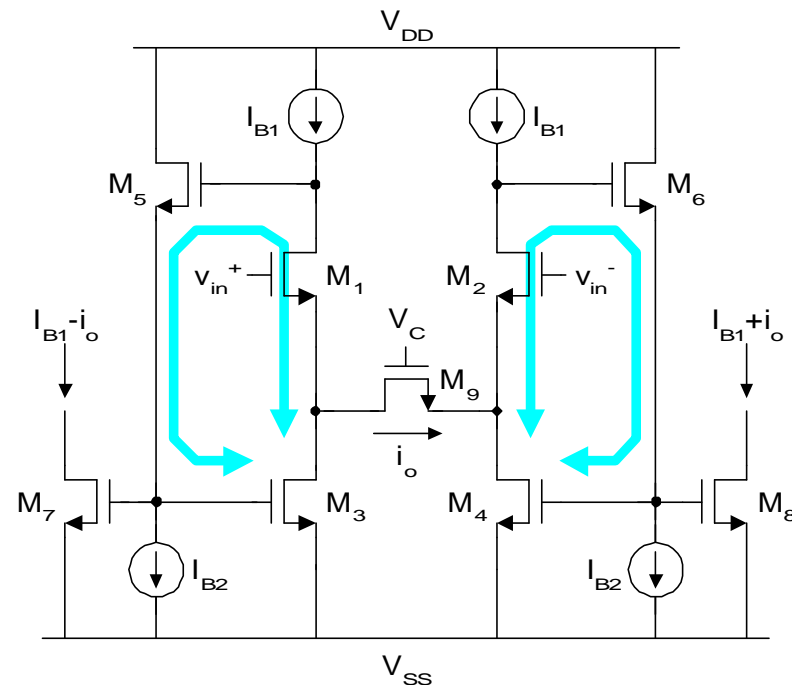
for large β and small $\sqrt{i_1} - \sqrt{i_2}$

$$v_{gs1} - v_{gs2} = (V_{TH} + \sqrt{2i_1/\beta}) - (V_{TH} + \sqrt{2i_2/\beta}) = \sqrt{2/\beta}(\sqrt{i_1} - \sqrt{i_2}) \approx 0$$

$$\therefore G_m \equiv \frac{\partial i_{out}}{\partial \Delta v_{in}} = \frac{i_{out}}{\Delta v_{in}} \cong \frac{2}{R_C}$$



● Differential Pair w/ **Degenerate Resistor & Feedback** Example



Negative feedback loops (M_1 - M_5 - M_3 & M_2 - M_6 - M_4) forces constant currents I_{B1} to flow through M_1 and M_2 $\rightarrow v_{gs1} = v_{gs2}$

TC Amp using MOS in Saturation

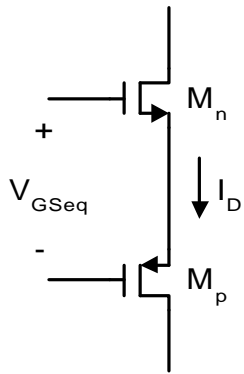
- Current in Saturation MOSFET

$$i_{ds} = \frac{\beta}{2} (v_{gs} - V_{TH})^2$$

- Basic Principle

$$A^2 - B^2 = (A + B) \cdot (A - B) = k \cdot (v_{in}^+ - v_{in}^-)$$

- Composite Transistor

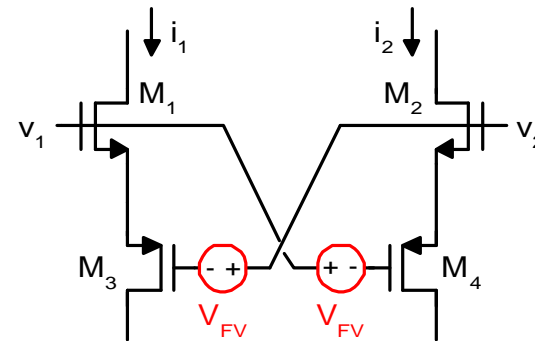


$$I_D = \frac{\beta_{eq}}{2} (V_{GSeq} - V_{THeq})^2$$

$$V_{GSeq} \equiv V_{GSN} + V_{SGP}$$

$$V_{THeq} \equiv V_{THN} + |V_{THP}|$$

$$\beta_{eq} \equiv \frac{1}{2} \frac{\beta_N \beta_P}{(\sqrt{\beta_N/2} + \sqrt{\beta_P/2})^2}$$



$$i_{out} = 2\beta_{eq} [V_{FV} - V_{THeq}] \cdot (v_1 - v_2)$$

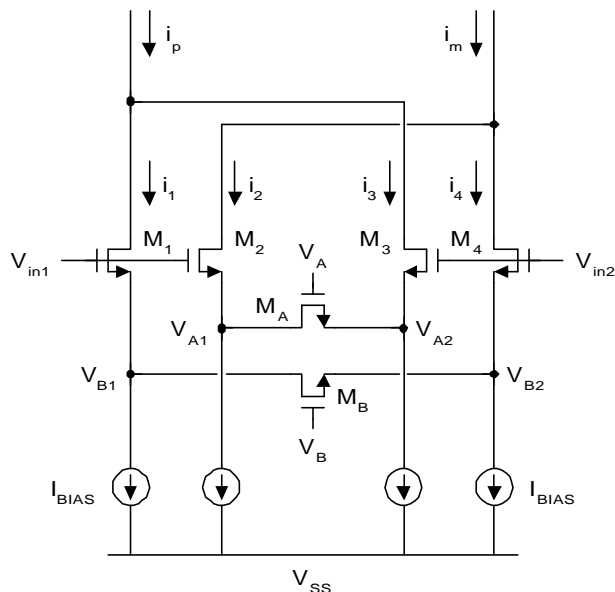


TC Amp using MOS in Linear

● **Current in Saturation MOSFET**
$$i_{ds} = \beta \left[(v_{gs} - V_{TH}) v_{ds} - \frac{1}{2} v_{ds}^2 \right]$$

● **Basic Principle**
$$(A - C^2) - (B - C^2) = A - B \propto v_{in}^+ - v_{in}^-$$

● **Example**

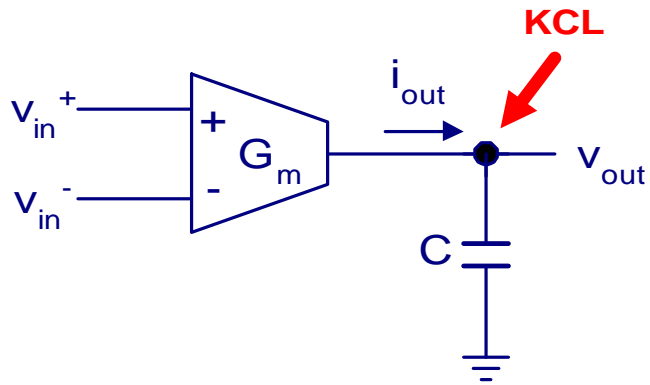


$$i_{out} = i_p - i_m = (i_1 + i_3) - (i_2 + i_4) = (i_1 - i_4) - (i_2 - i_3)$$

$$i_1 - i_4 = 2i_B = 2\beta \left[(V_B - V_{B2} - V_{TH})(V_{B1} - V_{B2}) - \frac{1}{2}(V_{B1} - V_{B2})^2 \right]$$

$$i_2 - i_3 = 2i_A = 2\beta \left[(V_A - V_{A2} - V_{TH})(V_{A1} - V_{A2}) - \frac{1}{2}(V_{A1} - V_{A2})^2 \right]$$

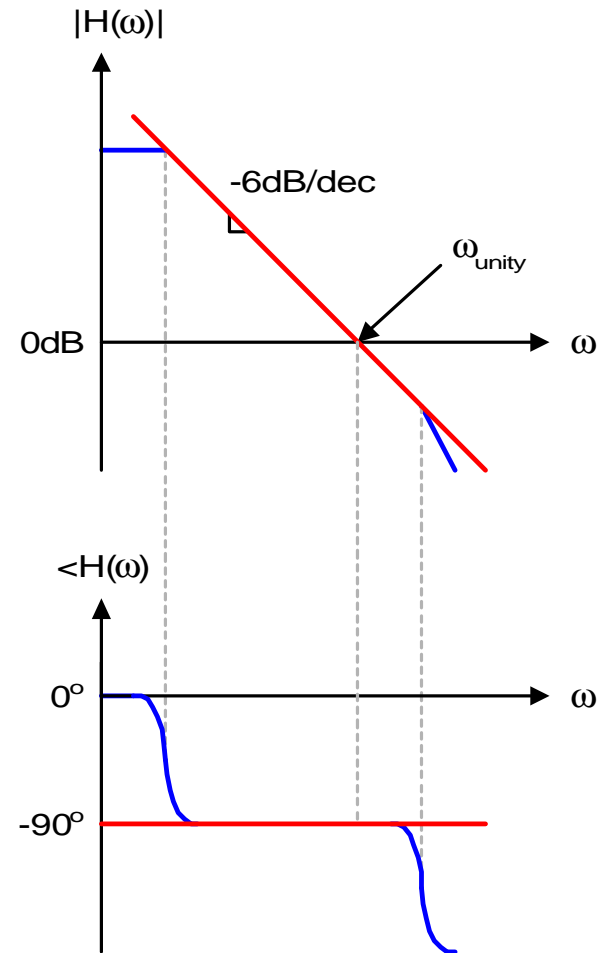
G m-C Integrator



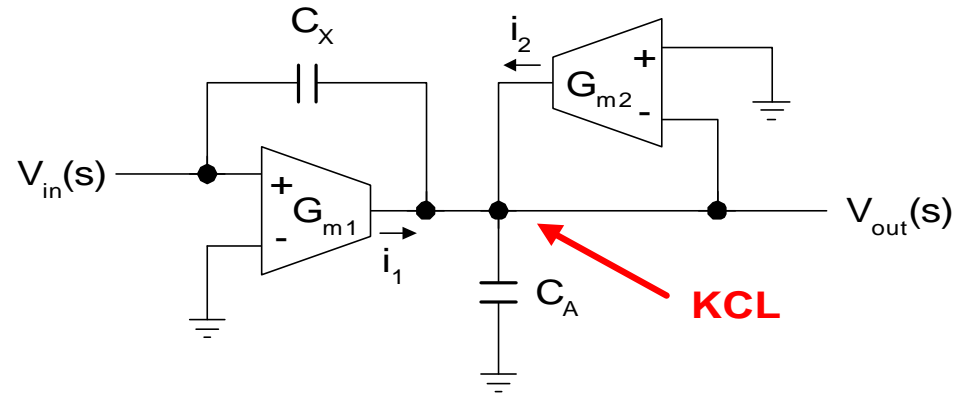
$$H(s) \equiv \frac{v_{out}}{v_{in}} = \frac{G_m}{sC}$$

$$\omega_{unity} = \frac{G_m}{C}$$

critical parameters to determine filter frequency characteristics



1st-Order Gm-C Filter



$$H(s) \equiv \frac{V_{out}(s)}{V_{in}(s)} = \frac{\left(\frac{C_X}{C_A + C_X} \right) s + \left(\frac{G_{m1}}{C_A + C_X} \right)}{s + \left(\frac{G_{m2}}{C_A + C_X} \right)} \leftarrow \frac{k_1 s + k_0}{s + \omega_0}$$

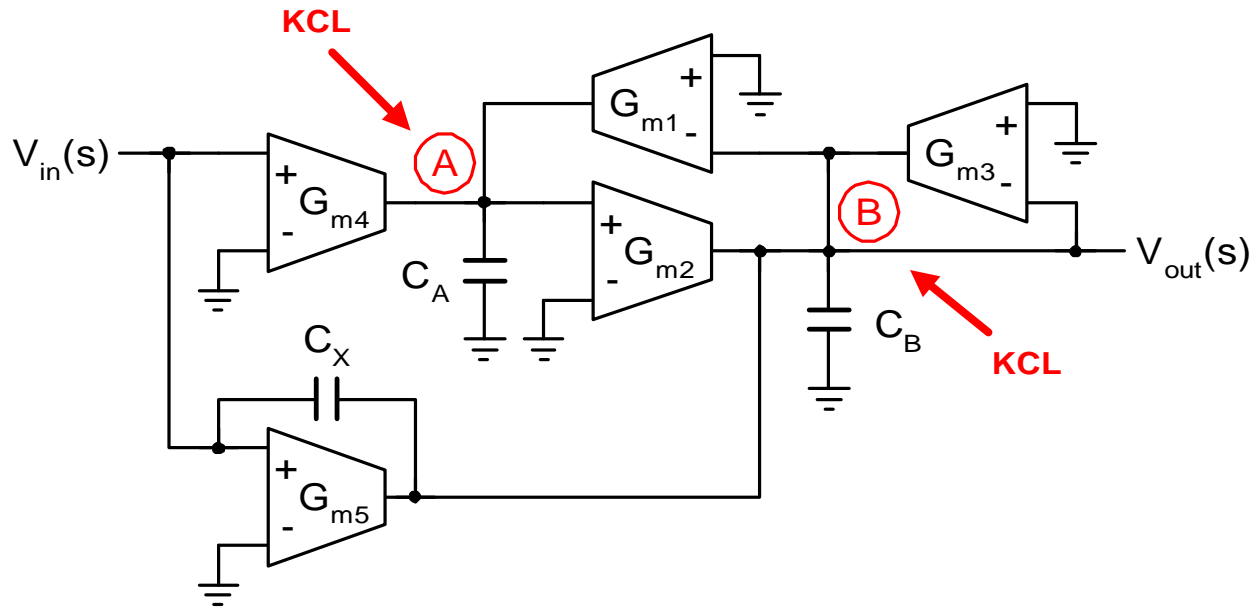
$$G_{m1} = k_0 \cdot (C_A + C_X)$$

$$G_{m2} = \omega_0 \cdot (C_A + C_X)$$

$$C_X = \frac{k_1}{1 - k_1} C_A$$



2nd-Order Gm-C Filter (Biquad)



$$H(s) \equiv \frac{V_{out}(s)}{V_{in}(s)} = \frac{\left(\frac{C_X}{C_B + C_X}\right)s^2 + \left(\frac{G_{m5}}{C_B + C_X}\right)s + \frac{G_{m2}G_{m4}}{C_A(C_B + C_X)}}{s^2 + \left(\frac{G_{m3}}{C_B + C_X}\right)s + \frac{G_{m1}G_{m2}}{C_A(C_B + C_X)}} \leftarrow \frac{k_2s^2 + k_1s + k_0}{s^2 + \left(\frac{\omega_0}{Q}\right)s + \omega_0^2}$$



● Characteristic Function

$$\text{denominator } r = s^2 + \left(\frac{\omega_0}{Q} \right) s + \omega_0^2$$

$$\omega_0 = \sqrt{\frac{G_{m1} G_{m2}}{C_A (C_B + C_X)}}$$

$$Q = \sqrt{\frac{G_{m1} G_{m2} (C_B + C_X)}{G_{m3}^2 C_A}}$$

● Filtering Operations

$$k_2 = \frac{C_X}{C_B + C_X} \quad k_1 = \frac{G_{m5}}{C_B + C_X} \quad k_0 = \frac{G_{m2} G_{m4}}{C_A (C_B + C_X)}$$

✓ Lowpass $k_2 = k_1 = 0$

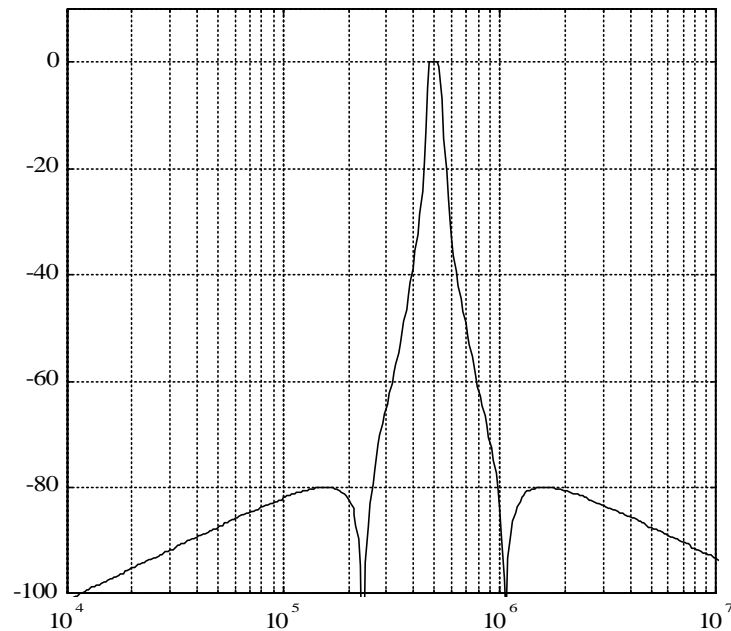
✓ Highpass $k_1 = k_0 = 0$

✓ Bandpass $k_2 = k_0 = 0$

High-Order Gm-C Filter w/ Biquads

6th-order Elliptic BPF

- ✓ Passband : 480kHz ~ 520kHz
- ✓ Passband Ripple : < 0.05dB
- ✓ Stopband Attenuation : > 80dB



● $H_1(s)$

$$G_{m1} = G_{m2} = 17.06\mu, G_{m3} = 0.80\mu$$

$$G_{m4} = 4.18\mu, G_{m5} = 0\mu$$

$$C_A = C_B = 5p, C_X = 0.319p$$

● $H_2(s)$

$$G_{m1} = G_{m2} = 16.19\mu, G_{m3} = 1.52\mu$$

$$G_{m4} = 0.21\mu, G_{m5} = 0\mu$$

$$C_A = C_B = 5p, C_X = 0.319p$$

● $H_3(s)$

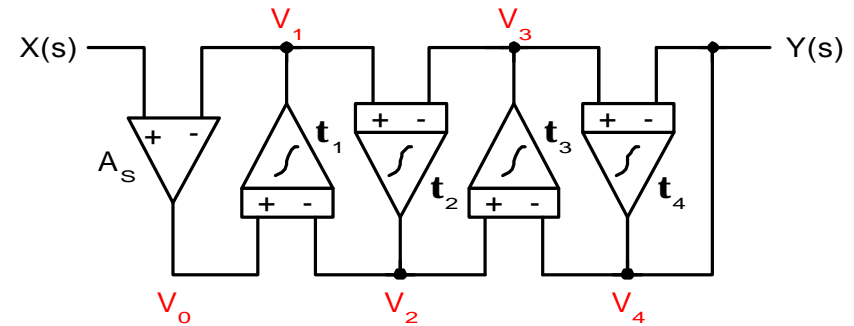
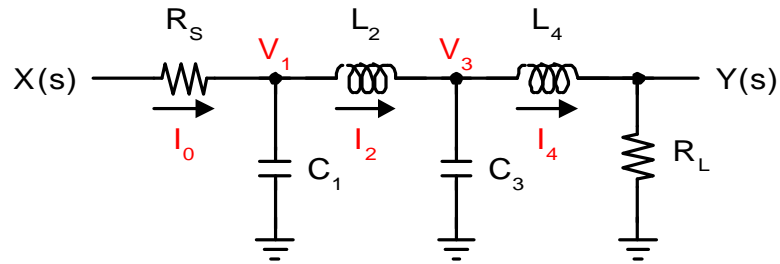
$$G_{m1} = G_{m2} = 14.89\mu, G_{m3} = 0.67\mu$$

$$G_{m4} = 0\mu, G_{m5} = 1.89\mu$$

$$C_A = C_B = 5p, C_X = 0p$$



High-Order Gm-C Filter from RLC



$$\begin{aligned}
 I_0 &= (X - V_1)/R_s \\
 V_1 &= (I_0 - I_2)/sC_1 \\
 I_2 &= (V_1 - V_3)/sL_2 \\
 V_3 &= (I_2 - I_4)/sC_3 \\
 I_4 &= (V_3 - I_4 R_L)/sL_2
 \end{aligned}$$

$$\begin{aligned}
 V_0 &= A_s (X - V_1) \\
 V_1 &= (V_0 - V_2)/s\tau_1 \\
 V_2 &= (V_1 - V_3)/s\tau_2 \\
 V_3 &= (V_2 - V_4)/s\tau_3 \\
 V_4 &= (V_3 - Y)/s\tau_4
 \end{aligned}$$

Frequency Transformation & Impedance Transformation Required



Non-Idealities

● **Finite Output Resistance** $H(s) = \frac{G_m R_{out}}{1 + sR_{out} C}$

- ✓ Finite DC Gain : BPF, HPF
- ✓ Reduced Phase ($> -90^\circ$): Q decreases
- ✓ Cascode Output Stage & Compensation Technique

● **Finite Parasitic Pole Frequency** $H(s) = \frac{G_m R_{out}}{1 + sR_{out} C} \cdot \frac{1}{1 + s/p_{internal}}$

- ✓ Increased Phase ($< -90^\circ$): Q increases
- ✓ Careful Design

● **Input Capacitance Loading** $H(s) = \frac{G_m}{s(C + C_{input})}$

- ✓ Frequency Change
- ✓ Dummy Cells

Linearity Problems

● **Nonlinearity** $I_{\text{out}}(t) \equiv a_1 V_{\text{in}}(t) + a_2 [V_{\text{in}}(t)]^2 + a_3 [V_{\text{in}}(t)]^3 + \dots$

● **Harmonic Distortion** $V_{\text{in}}(t) = A \sin(\omega_0 t)$

$$I_{\text{out}}(t) = I_1 \sin(\omega_0 t) + I_2 \sin(2\omega_0 t) + I_3 \sin(3\omega_0 t) + \dots$$

$$\text{THD [dB]} \equiv 10 \log \left(\frac{I_2^2 + I_3^2 + I_4^2 + \dots}{I_1^2} \right)$$

● **Inter Modulation Distortion** $V_{\text{in}}(t) = A[\sin(\omega_1 t) + \sin(\omega_2 t)]$, $\omega_1 \approx \omega_2$

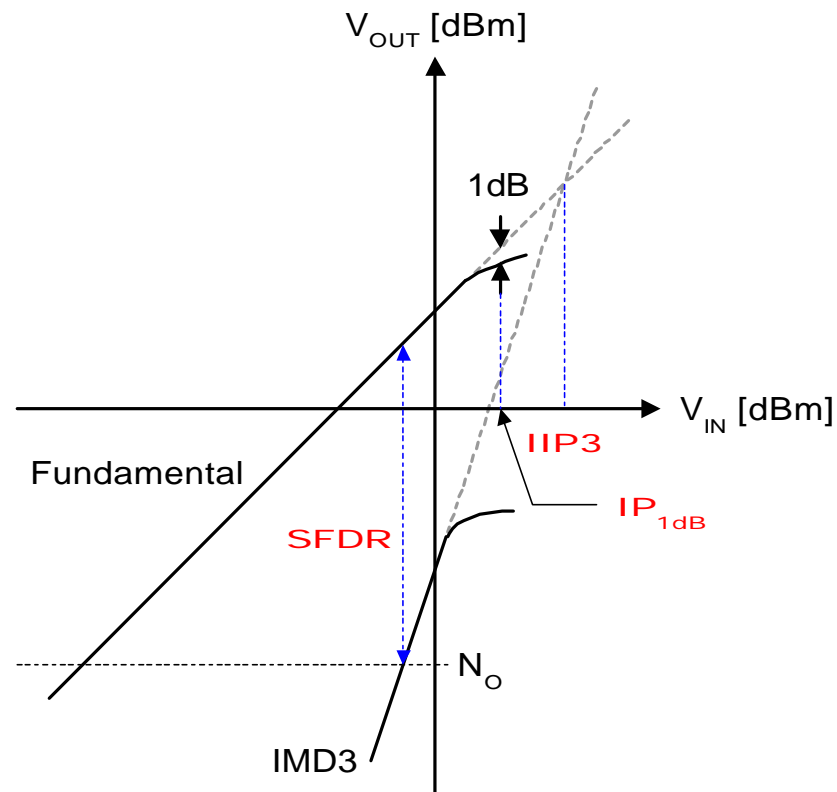
✓ IMD2 $\rightarrow \omega_1 + \omega_2, \omega_1 - \omega_2$

✓ IMD3 $\rightarrow \omega_1 + 2\omega_2, 2\omega_1 + \omega_2, 2\omega_1 - \omega_2, \omega_1 - 2\omega_2$



Dynamic Range Performance

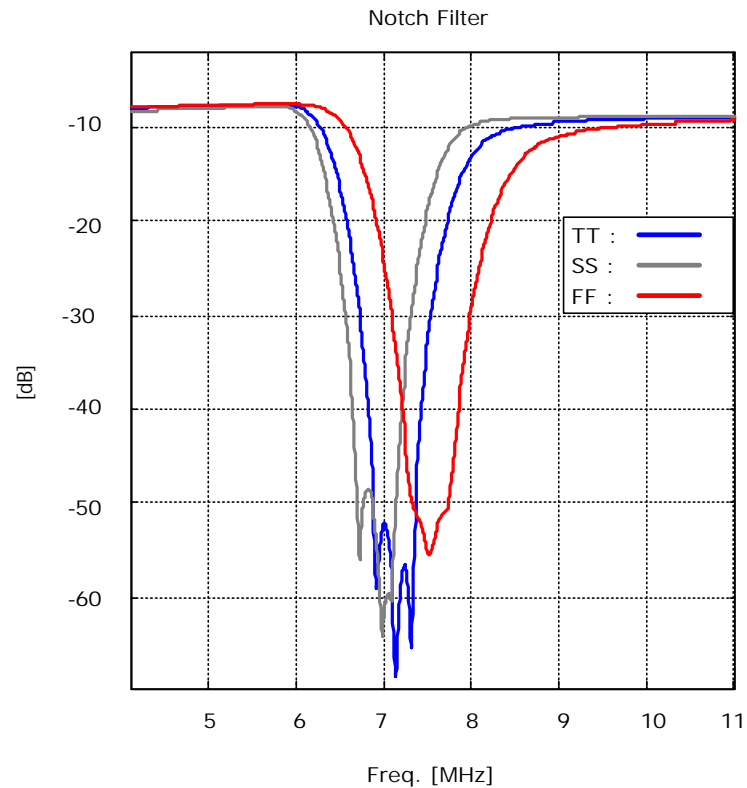
- IIP3 : Input-Referred Third-Order Intercept Point
- IP_{1dB} : Input-Referred 1-dB Compression Point
- SFDR : Spurious-Free Dynamic Range



Gm Variations

- Values of G_m might change due to

process variation, temperature, aging, ...

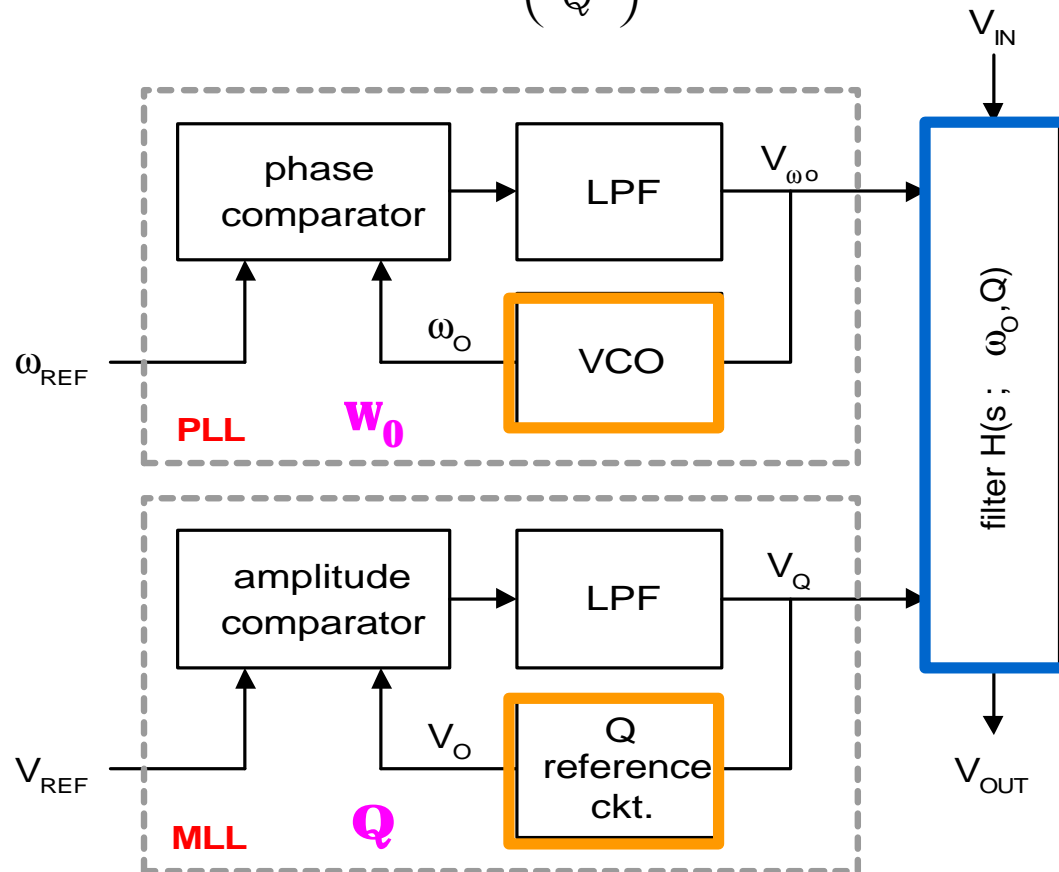


- freq. change
- Q change

- **Trimming** after chip fabrication possible, but one-time event.

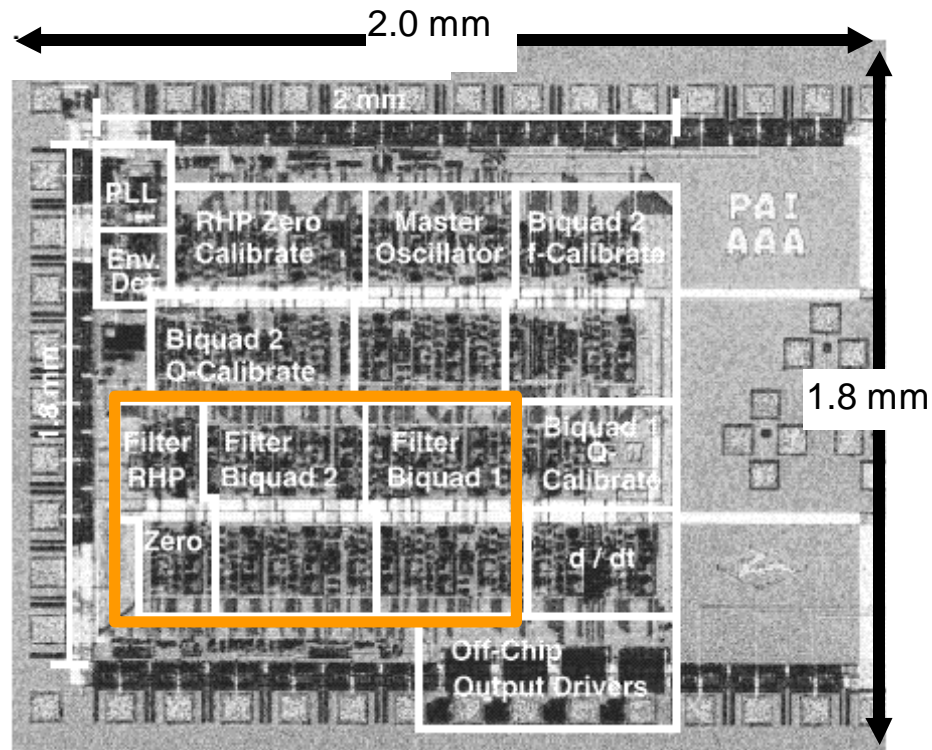
On-Chip Tuning Example for Biquad

$$H(s) = \frac{D(s)}{s^2 + \left(\frac{\omega_0}{Q}\right)s + \omega_0^2}$$



Recent Advance Example 1

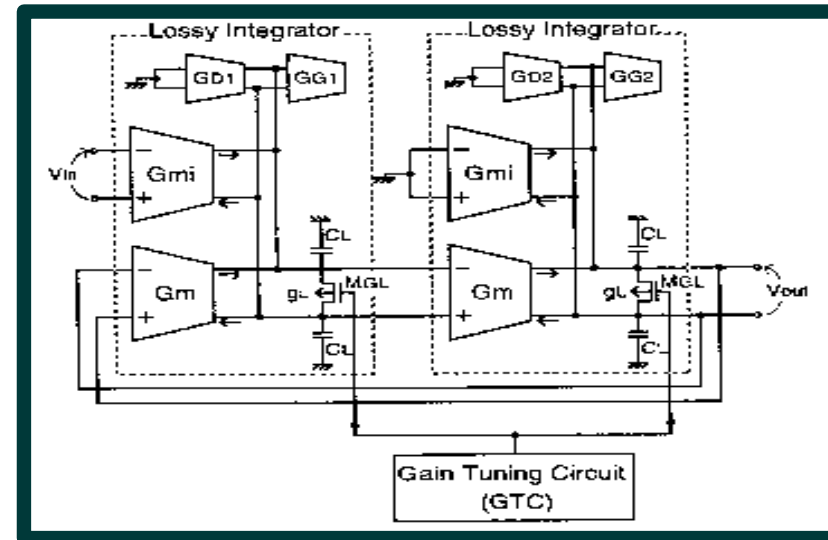
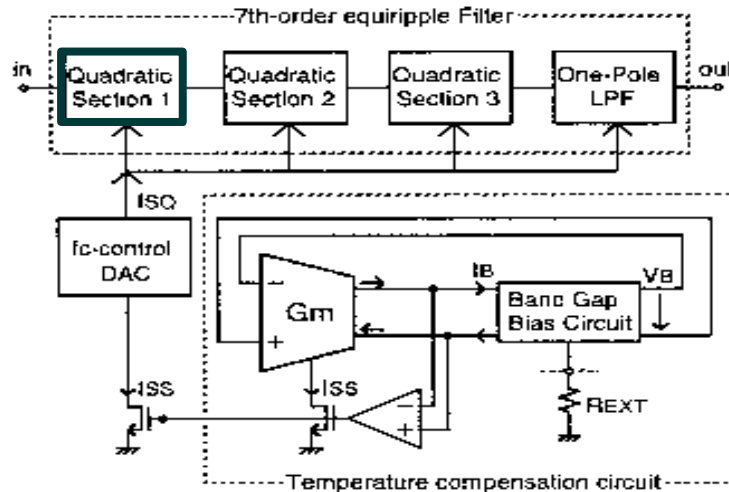
55 Mbps Equalizer for Magnetic Storage Read Channels



- 4-pole & 1-zero
- Equalization
- for Peak-Detect Scheme
- 2.0- μm CMOS Technology
- SNR > 57 dB, THD < 1%
- Power = 40 mW
- UCLA (📖 *IEEE JSSC*, 1994)

Recent Advance Example 2

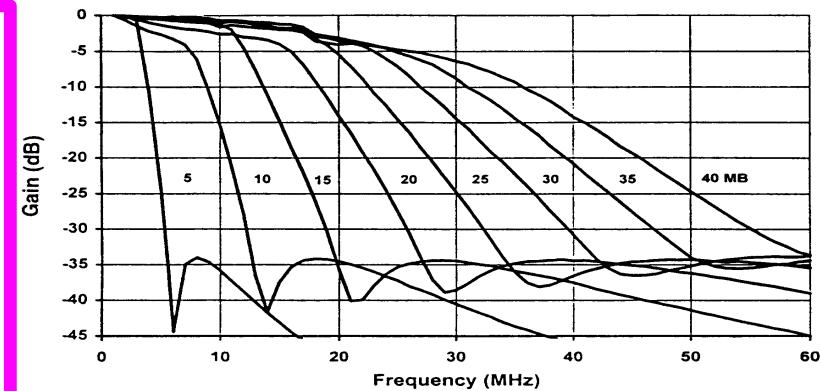
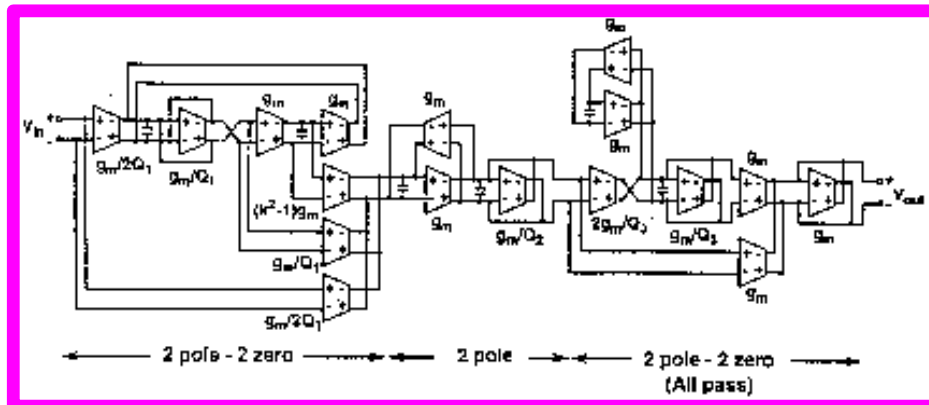
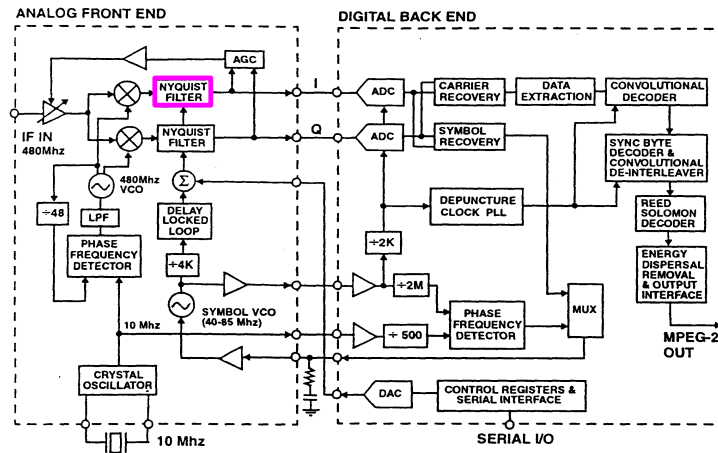
7-th Order Equiripple Gm-C Filter



- 0.4- μm CMOS Technology
- $f_{\text{cutoff}} = 50 \text{ MHz}$
- THD < 1 %, Power = 100 mW (3 V)
- Hitachi (📖 *IEEE ISSCC*, 1997)

Recent Advance Example 3

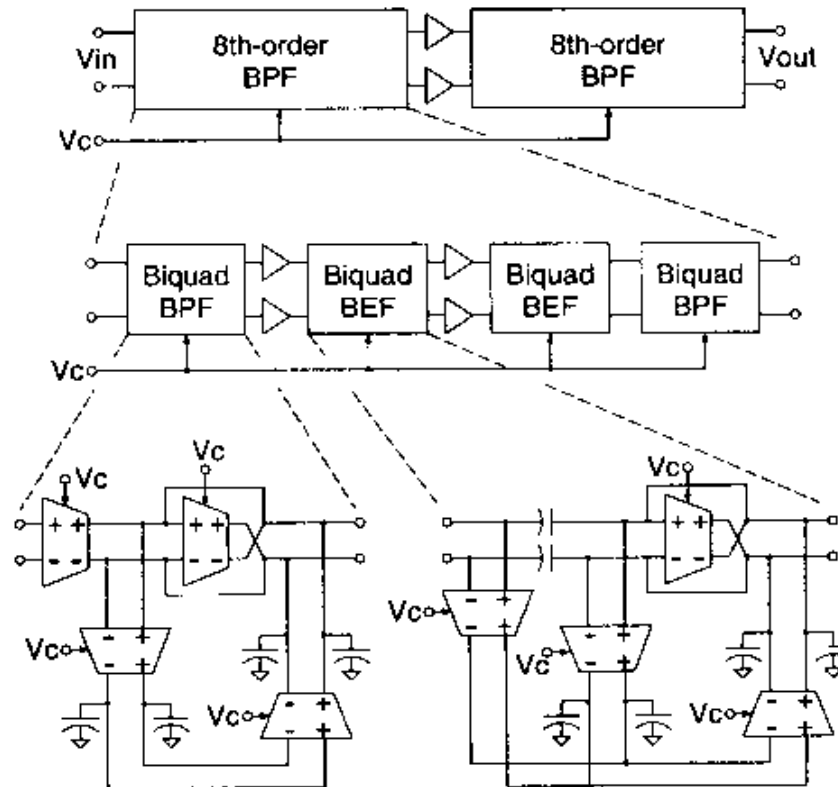
Raised-Cosine Matched Filter for 480 MHz QPSK Demodulator for DBS




Analog Devices (IEEE ISSCC, 1997)

Recent Advance Example 4

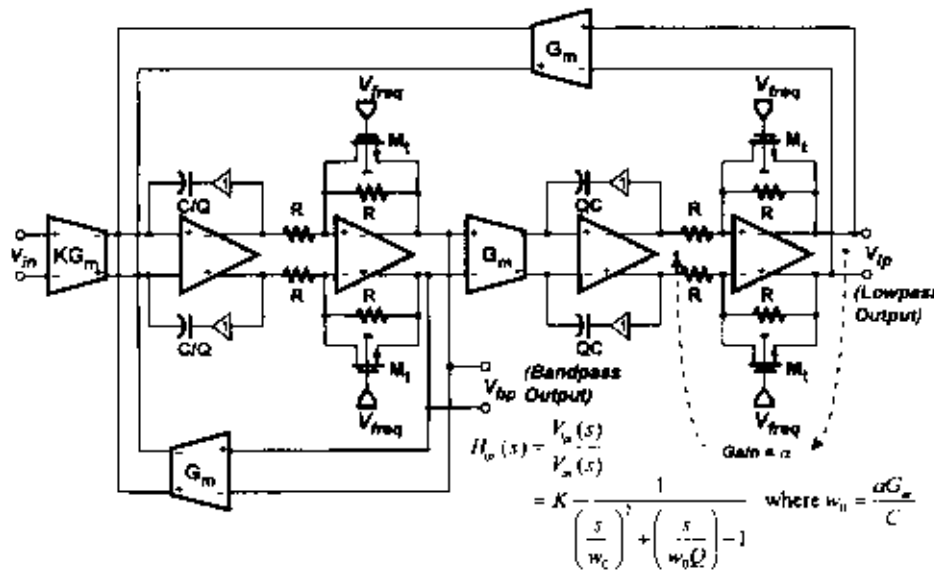
16th-order BPF for J-PDC



- 2 x 8th-order BPF
- Average of f_0 : 450.5kHz
- σ of f_0 : ± 1.5 kHz
- Tuning Range of f_0 : 240~770kHz
- 0.35- μ m CMOS
- Power : 4.8mA @ 2.5V
- Active Area : 2.5mm²
- Fujitsu
( IEEE ISSCC, 1999)

Recent Advance Example 5

7th-order Equiripple Group Delay LPF



- 1 + 3 x Biquads
 - f_{3dB} : 450.5kHz
 - f_{3dB} Accuracy: $\pm 10\%$
 - Group Delay Acc. : $\pm 5\%$
 - 0.25- μm CMOS
 - Power Supply : 2.5V
 - Chip Area : 3mm²
 - Texas Instruments
- (IEEE ISSCC, 1999)